

Unipolar Hall Switch

Low Sensitivity

Features and Benefits

- Wide operating voltage range from 3.5V to 24V
- Low sensitivity
- CMOS technology
- Chopper-stabilized amplifier stage
- Low current consumption
- Open drain output
- Thin SOT23 3L and flat TO-92 3L both RoHS Compliant packages

Applications

- Automotive, Consumer and Industrial
- Solid-state switch
- Interrupter
- Current detector
- Proximity detection

Ordering information

Part No.	Temperature Code	Package Code	Option Code	Packing Form Code
US5881	E	UA	AAA-000	BU
US5881	L	UA	AAA-000	BU
US5881	E	SE	AAA-000	RE
US5881	L	SE	AAA-000	RE

Legend

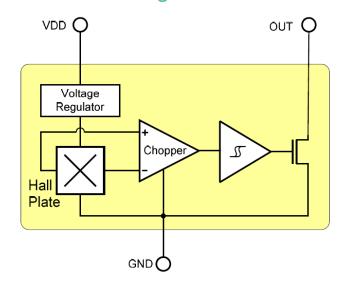
Temperature Code: L for Temperature Range -40°C to 150°C

E for Temperature Range -40°C to 85°C

Package Code: UA for TO-92(Flat), SE for TSOT3

Packing Form: RE for Reel, BU for Bulk Ordering example: US5881EUA-AAA-000-BU

1. Functional Diagram



2. General Description

The Melexis US5881 is a unipolar Hall-effect switch designed in mixed signal CMOS technology.

The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, Schmitt trigger and an open-drain output driver, all in a single package.

Thanks to its wide operating voltage range and extended choice of temperature range, it is suitable for use in automotive and solid state switch applications.

The device is delivered in a Thin Small Outline Transistor (TSOT) for surface mount process and

in a Plastic Single In Line (TO-92 flat) for throughhole mount

Both 3-lead packages are RoHS compliant.

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3. Glossary of Terms

MilliTesla (mT), Gauss Units of magnetic flux density:

1mT = 10 Gauss

RoHS Restriction of Hazardous Substances

TSOT Thin Small Outline Transistor (TSOT package) – also referred with the Melexis package

code "SE"

ESD Electro-Static Discharge
BLDC Brush-Less Direct-Current

4. Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage	V_{DD}	20	V
Supply Current	I_{DD}	50	mA
Output Voltage	V _{OUT}	20	V
Output Current	I _{OUT}	50	mA
Storage Temperature Range	T _S	-50 to 150	°C
Maximum Junction Temperature	T _J	165	°C

Table 1: Absolute maximum ratings

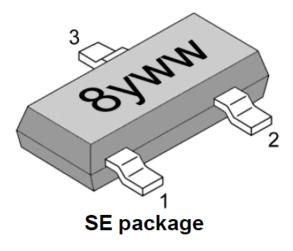
Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

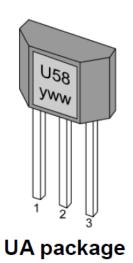
Operating Temperature Range	Symbol	Value	Units
Temperature Suffix "E"	T _A	-40 to 85	°C
Temperature Suffix "L"	T _A	-40 to 150	°C

5. Pin Definitions and Descriptions

SE Pin No	UA Pin No	Name	Туре	Function
1	1	VDD	Supply	Supply Voltage
2	3	OUT	Output	Open Drain
3	2	GND	Ground	Ground pin

Table 2: Pin definitions and descriptions





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6. General Electrical Specifications

DC Operating Parameters $T_A = 25^{\circ}C$, $V_{DD} = 12V$ (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	V_{DD}	Operating	3.5		24	V
Supply Current	I_{DD}	$B < B_{RP}$	1.5	2.5	5	mA
Output Saturation Voltage	V_{DSon}	$I_{OUT} = 20$ mA, $B > B_{OP}$		0.4	0.5	V
Output Leakage Current	I _{OFF}	$B < B_{RP}$, $V_{OUT} = 24V$		0.01	10	μΑ
Output Rise Time	t _r	$R_L = 1k\Omega$, $C_L = 20pF$		0.25		μs
Output Fall Time	t_f	$R_L = 1k\Omega$, $C_L = 20pF$		0.25		μs
Maximum Switching Frequency	F_{SW}			10		KHz
SE Package Thermal Resistance	R_{TH}	Single layer (1S) Jedec board		301		°C/W
UA Package Thermal Resistance	R_{TH}			200		°C/W

Table 3: Electrical specifications

7. Magnetic Specifications

DC Operating Parameters T_A = -40 °C to 125 °C, V_{DD} = 3.5V to 7V (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Operating Point	B_{OP}		15	25	30	mT
Release Point	B_RP		9.5	20	28	mT
Hysteresis	B _{HYST}		2	4.3	5.5	mT

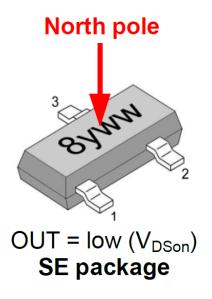
Table 4: Magnetic specifications

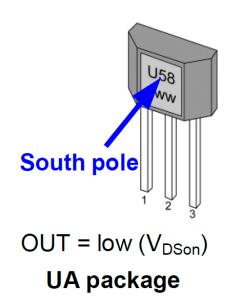
8. Output Behaviour versus Magnetic Pole

DC Operating Parameters T_A = -40 °C to 150 °C, V_{DD} = 3.5V to 24V (unless otherwise specified)

Parameter	Test Conditions (SE)	OUT (SE)	OUT (UA)
South pole	$B > B_{OP}$	High	Low
Null or weak magnetic field	$B \rightarrow 0 \text{ or } B < B_{RP}$	High	High
North pole	B > B _{OP}	Low	High

Table 5: Output behaviour versus magnetic pole







9. Detailed General Description

Based on mixed signal CMOS technology, Melexis US5881 is a Hall-effect device with low magnetic sensitivity. Its sensitivity enables high accuracy in position sensing by the use of small air gap.

The chopper-stabilized amplifier uses switched capacitor technique to suppress the offset generally observed with Hall sensors and amplifiers. The CMOS technology makes this advanced technique possible and contributes to smaller chip size and lower current consumption than bipolar technology. The small chip size is also an important factor to minimize the effect of physical stress.

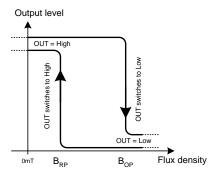
This combination results in more stable magnetic characteristics and enables faster and more precise design.

The wide operating voltage from 3.5V to 24V, "L" and "E" operating temperature range and low current consumption make this device especially suitable for automotive solid state switch applications.

The output signal is open-drain type. Such output allows simple connectivity with TTL or CMOS logic by using a pull-up resistor tied between a pull-up voltage and the device output.

10. Unique Features

The US5881 exhibits unipolar magnetic switching characteristics. Therefore, it operates only with one magnetic pole.



Unipolar switch characteristic

The UA package is south pole active:

Applying a south magnetic pole greater than B_{OP} facing the branded side of the package switches the output low.

The SE package is north pole active:

Applying a north magnetic pole greater than B_{OP} facing the branded side of the package switches the output low.

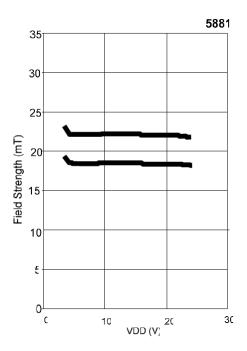
Removing the magnetic field (B \rightarrow 0) switches the output high. The use of the opposite magnetic pole facing the branded side does not affect the output state.

A magnetic hysteresis B_{HYST} keeps B_{OP} and B_{RP} separated by a minimal value. This hysteresis prevents output oscillation near the switching point.

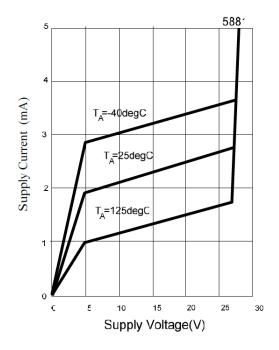
Melexis

11. Performance Graphs

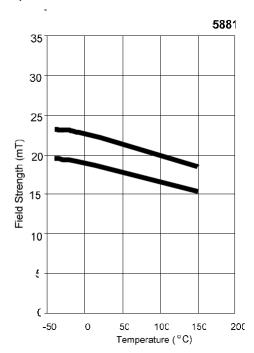
11.1. Typical Magnetic Switch Points vs V_{DD}



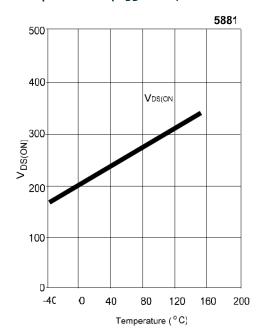
11.3. Typical Supply Current vs V_{DD}



11.2. Magnetic Switch Points vs Temperature



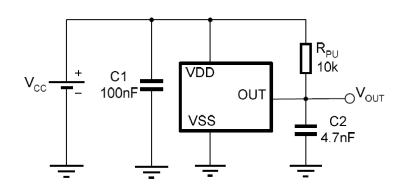
11.4. Typical Saturation Voltage vc Temperature (V_{DD}=12V; lout=20mA)



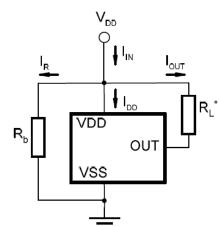


12. Application Information

12.1. Typical Three-Wire Application Circuit

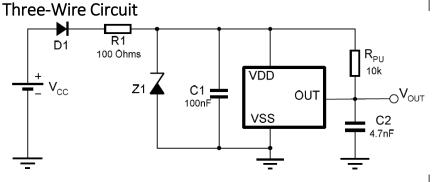


12.2. Two-Wire Circuit



Note:

12.3. Automotive and Harsh, Noisy Environments



With this circuit, precise ON and OFF currents can be detected using only two connecting wires.

The resistors RL and Rb can be used to bias the input current. Refer to the part specifications for limiting values.

$$\begin{array}{ll} B_{RP}: & I_{OFF} = I_R \ + I_{DD} = V_{DD}/R_b + I_{DD} \\ B_{OP}: & I_{ON} = I_{OFF} + I_{OUT} = I_{OFF} + V_{DD}/R_L \end{array}$$

13. Application Comments

For proper operation, a 100nF bypass capacitor should be placed as close as possible to the device between the V_{DD} and ground pin.

For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the V_{DD} pin. When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum ($V_{CC}/R_1 \le 50mA$)
- the resulting device supply voltage V_{DD} has to be higher than V_{DD} min ($V_{DD} = V_{CC} R_1 \cdot I_{DD}$) the resistor has to withstand the power dissipated in reverse voltage condition ($P_D = V_{CC}^2 / R_1$)

When using a diode, a reverse current cannot flow and the voltage drop is almost constant (≈0.7V).

Therefore, a $100\Omega/0.25W$ resistor for 5V application and a diode for higher supply voltage are recommended. Both solutions provide the required reverse voltage protection.

When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended that figure 13.3 from the Application Information section is used.

The low-pass filter formed by R₁ and C₁ and the zener diode Z₁ bypass the disturbances or voltage spikes occurring on the device supply voltage V_{DD} . The diode D_1 provides additional reverse voltage protection.

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14. Standard information regarding manufacturability of Melexis products with different soldering processes

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

- IPC/JEDEC J-STD-020
 - Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113
 - Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing (reflow profiles according to table 2)

Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20
 - Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15
 Resistance to soldering temperature for through-hole mounted devices

Iron Soldering THD's (Through Hole Devices)

EN60749-15
 Resistance to soldering temperature for through-hole mounted devices

Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

 EIA/JEDEC JESD22-B102 and EN60749-21 Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: http://www.melexis.com/quality.aspx

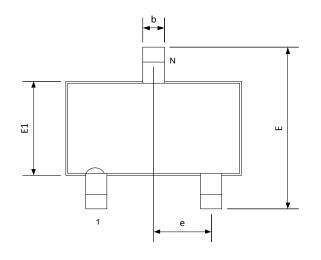
15. ESD Precautions

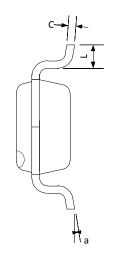
Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.



16. Package Information

16.1. SE Package (TSOT-3L)





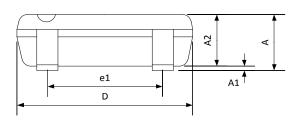
Notes:

- Dimension "D" and "E1" do not include mold flash or protrusions. Mold flash or protrusion shall not exceed 0.15mm on "D" and 0.25mm on "E" per side.
- 2. Dimension "b" does not include dambar protrusion.

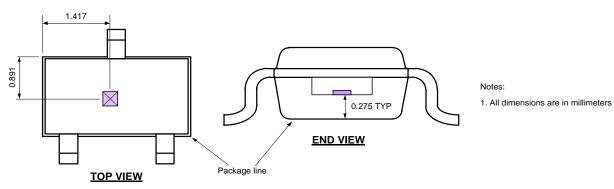
Marking:

Top side : 8yww

8 = part number (US5881) y = last digit of year ww = calendar week



Hall plate location

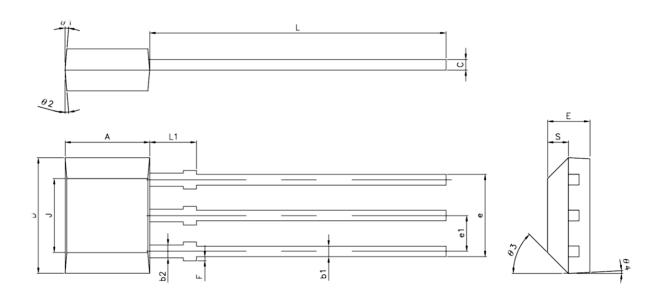


This table in mm

N	1		Α	A1	A2	D	E	E1	L	b	С	е	e1	α
2		min	_	0.025	0.85	2.80	2.60	1.50	0.30	0.30	0.10	0.95	1.90	0°
3	'	max	1.00	0.10	0.90	3.00	3.00	1.70	0.50	0.45	0.20	BSC	BSC	8°



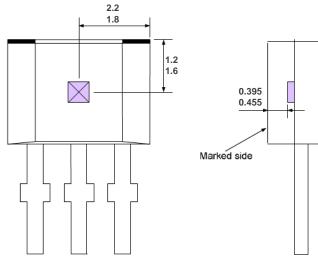
16.2. UA Package (TO-92 flat)



Notes:

- 1. Mold flashes and protrusion are not included.
- 2. Gate burrs shall not exceed 0.127um on the top side.

Hall plate location



Notes:

1. All dimensions are in millimeters

Marking:

1st Line: U58 - Part number (US5881)

2nd Line: yww

y - last digit of year ww - calendar week

This table in mm

	Α	D	E	F	J	L	L1	S	b1	b2	С	е	e1
min	2.80	3.90	1.40	0.00	2.51	14.0	1.55	0.63	0.35	0.43	0.35	2.51	1.24
max	3.20	4.30	1.60	0.20	2.72	15.0	1.75	0.84	0.44	0.52	0.44	2.57	1.30
	θ1	θ2	θ3	θ4									
min	5°	5°	45°	3°									
max	MAX	REF	REF	REF									

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17. Contact

For the latest version of this document, go to our website at www.melexis.com.

For additional information, please contact our Direct Sales team and get help for your specific needs:

Europe, Africa	Telephone: +32 13 67 04 95
	Email: sales_europe@melexis.com
Americas	Telephone: +1 603 223 2362
	Email: sales_usa@melexis.com
Asia	Email: sales_asia@melexis.com

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